

8-bit Proprietary Microcontrollers

CMOS

F²MC-8L MB89590B/BW Series

MB89593B/595B/P595B/ MB89593BW/595BW/P595BW

■ DESCRIPTION

The MB89590B/BW series is a line of general-purpose, single-chip microcontrollers. In addition to a compact instruction set, these microcontrollers contain a variety of peripheral functions, such as PLL clock control, timers, a serial interface, a PWM timer, the USB hub function, and the USB function. The USB hub function, in particular, supports five ports (one of them is dedicated to an internal function) allowing them to interface with other USB devices. The microcontrollers also contain one USB function channel to support high speeds.

■ FEATURES

- **Package type**

64-pin LQFP package (0.5 mm pitch)

- **High-speed operations at low voltage**

Minimum execution time : 0.33 μ s (Automatically generates a 12 MHz main clock and a 48 MHz USB interface synchronization clock with an externally supplied 6 MHz clock and the internal PLL circuit.)

- **F²MC-8L CPU core**

Instruction set that is optimum to the controllers

Multiplication and division instructions,

16-bit arithmetic operations,

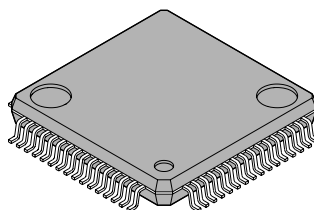
Branch instructions by bit testing,

Bit manipulation instructions, etc.

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■ PACKAGE

64-pin plastic LQFP



(FPT-64P-M03)

MB89590B/BW Series

(Continued)

- **PLL clock control**

The internal PLL clock circuit allows the use of low-speed clocks which are advantageous to noise characteristics.

(6 MHz externally supplied clock : Internal system clock oscillated at 12 MHz)

- **Various timers**

8-bit PWM timer (can be used as either 8-bit PWM timer × 2 channels or PPG timer × 1 channel)

Internal 21-bit timebase timer

- **Internal USB transceiver circuit (Compatible with high and low speeds)**

- **USB hub**

Compliant to USB Protocol Revision 1.0

Five downstream port channels (One of these channels is dedicated to a function.)

Automatically responds to all USB protocols by hardware.

Descriptor configuration information is provided as ROM data for automatic responding by hardware (vendor ID and product ID) .

* String data is not supported.

Allows switching between BUS power supply and own power supply modes.

Power supply to the USB down ports is controlled port by port.

- **USB function**

Compliant to USB Protocol Revision 1.0

Support for full speed

Allows four endpoints to be specified at maximum.

Types of transfer supported : control/interrupt/bulk/isochronous

Built-in DMAC (Maps the buffer for each endpoint on to the internal RAM to directly access the memory for function's send and receive data.)

- **UART/serial interface**

Built-in UART/SIO function (selectable by switching)

- **External interrupt**

External interrupt (level detection × 8 channels)

Eight inputs are independent of one another and can also be used for resetting from low-power consumption mode (the L-level detection feature available) .

- **Low power consumption (standby mode supported)**

Stop mode (There is almost no current consumption since oscillation stops.)

Sleep mode (This mode stops the running CPU.)

- **A maximum of 45 general-purpose I/O ports**

General-purpose I/O ports (CMOS) : 34

General-purpose output ports (CMOS) : 8

General-purpose I/O ports (Nch open drain) : 3

- **Power supply**

Supply voltage : 3.0 to 5.5 V

MB89590B/BW Series

■ PRODUCT LINEUP

Part number Parameter			MB89593B	MB89595B	MB89P595B	MB89593BW	MB89595BW	MB89P595BW
ROM size			8 KB	16 KB		8 KB	16 KB	
RAM size			512 B	1 KB		512 B	1 KB	
Package			LQFP-64 (FPT-64P-M03)					
Operation at USB reset			High impedance state			Low-level output		
Others			MASK product	MASK product	OTP/EVA product	MASK product	MASK product	OTP/EVA product
CPU functions			Number of instructions : 136 Instruction bit length : 8 bits Instruction length : 1 to 3 bytes Data bit length : 1, 8, and 16 bits Minimum execution time : 0. 33 μs (6 MHz) Interrupt processing time : 3 μs (6 MHz)					
Peripheral functions	General-purpose ports		General-purpose I/O ports (34 : CMOS; 3 : Nch open drain) General-purpose output ports (8 : CMOS)					
	USB hub		Upstream port : 1 channel Downstream port : 5 channels (One is dedicated to an internal function.) Port power supply control method : By individual port Allows selection between own power supply and bus power supply					
	USB function		Supports full speed. Four endpoints at maximum Built-in DMAC (Allows DMA transfer to the internal RAM)					
	PWM timer		8-bit PWM timer operation × 2 channels (can also be used as a PPG × 1 channel timer)					
	UART	SIO	Allows switching between UART (clock-synchronous/asynchronous data transfer allowed) and SIO (simple serial transfer) .					
	Timebase timer		21-bit timebase timer					
	Clock output		Allows output of two main clock divisions					
Standby mode			Sleep mode and Stop mode					

MB89590B/BW Series

■ DIFFERENCES AMONG PRODUCTS

1. Memory Size

Before evaluating using the OTP product, verify its differences from the product that will actually be used.

2. Current Consumption

When operated at low speeds, a product mounted with either one-time PROM or EPROM consumes more current than a product mounted with a mask ROM. However, in sleep/stop mode the current consumption is the same.

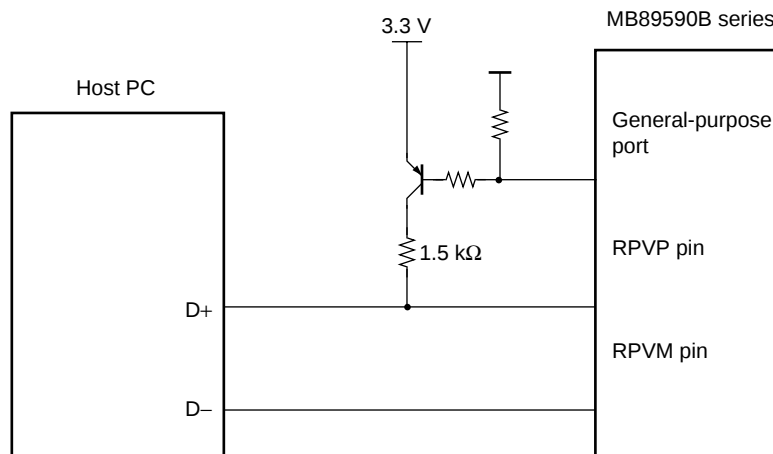
For detailed information on each package, see “■ PACKAGE DIMENSIONS.”

3. Differences Between the MB89590B series and the MB89590BW Series

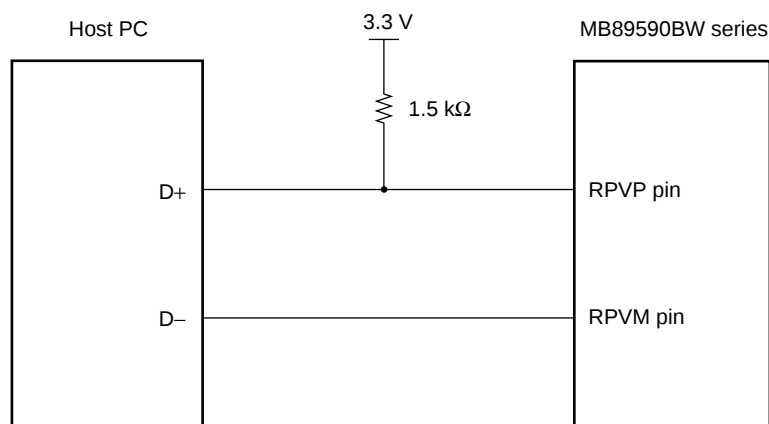
MB89590B series : Remains in high impedance state until USB connection takes place. Before the USB connection, use one general-purpose port output to control pullup resistance connection of this port by software.

MB89590BW series : Outputs at low level until USB connection takes place.

• Example MB89590B product connection

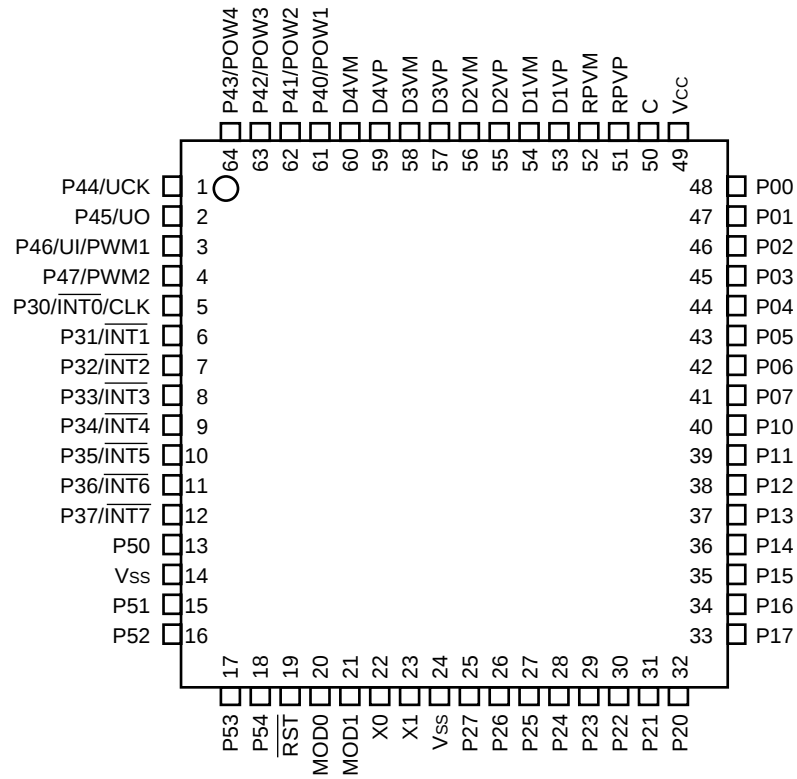


• Example MB89590BW product connection



PIN ASSIGNMENT

(TOP VIEW)



(FPT-64P-M03)

MB89590B/BW Series

■ PIN DESCRIPTION

Pin No.	Pin name	Circuit type	Function
1	P44/UCK	E	General-purpose CMOS I/O pin UART/S10 clock I/O
2	P45/UO	B	General-purpose CMOS I/O pin UART/S10 serial data output
3	P46/UI/ PWM1	E	General-purpose CMOS I/O pin UART/S10 serial data input PWM timer
4	P47/PWM2	B	General-purpose CMOS I/O pin PWM timer
5	P30/ $\overline{\text{INT0}}$ / CLK	E	General-purpose CMOS I/O pin Clock output pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
6	P31/ $\overline{\text{INT1}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
7	P32/ $\overline{\text{INT2}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
8	P33/ $\overline{\text{INT3}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
9	P34/ $\overline{\text{INT4}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
10	P35/ $\overline{\text{INT5}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
11	P36/ $\overline{\text{INT6}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
12	P37/ $\overline{\text{INT7}}$	E	General-purpose CMOS I/O pin This pin also serves as an external interrupt input pin. The external interrupt input is a hysteresis input. (Level detection)
13	P50	B	General-purpose CMOS I/O pin
14	V _{SS}	—	Power supply pin (GND)
15	P51	B	General-purpose CMOS I/O pin
16	P52	K	General-purpose Nch open drain I/O pin
17	P53	K	General-purpose Nch open drain I/O pin
18	P54	K	General-purpose Nch open drain I/O pin
19	$\overline{\text{RST}}$	I	Reset pin. (Reset on the negative logic low level.)

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MB89590B/BW Series

Pin No.	Pin name	Circuit type	Function
20	MOD0	F	An operating mode designation pin. Connect directly to Vss.
21	MOD1	F	An operating mode designation pin. Connect directly to Vss.
22	X0	A	Pins for the Crystal oscillator (6 MHz)
23	X1		
24	Vss	—	Power supply pin (GND)
25	P27	B	General-purpose CMOS output pin
26	P26	B	General-purpose CMOS output pin
27	P25	B	General-purpose CMOS output pin
28	P24	B	General-purpose CMOS output pin
29	P23	B	General-purpose CMOS output pin
30	P22	B	General-purpose CMOS output pin
31	P21	B	General-purpose CMOS output pin
32	P20	B	General-purpose CMOS output pin
33	P17	B	General-purpose CMOS I/O pin
34	P16	B	General-purpose CMOS I/O pin
35	P15	B	General-purpose CMOS I/O pin
36	P14	B	General-purpose CMOS I/O pin
37	P13	B	General-purpose CMOS I/O pin
38	P12	B	General-purpose CMOS I/O pin
39	P11	B	General-purpose CMOS I/O pin
40	P10	B	General-purpose CMOS I/O pin
41	P07	B	General-purpose CMOS I/O pin
42	P06	B	General-purpose CMOS I/O pin
43	P05	B	General-purpose CMOS I/O pin
44	P04	B	General-purpose CMOS I/O pin
45	P03	B	General-purpose CMOS I/O pin
46	P02	B	General-purpose CMOS I/O pin
47	P01	B	General-purpose CMOS I/O pin
48	P00	B	General-purpose CMOS I/O pin
49	Vcc	—	Power supply pin
50	C	—	Connect an external capacitor of 0.1 μ F. When using with 3.3 V power supply, connect this pin with the Vcc pin to set to 3.3 V input.
51	RPVP	USBDIV	USB route port + pin
52	RPVM	USBDIV	USB router port – pin

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MB89590B/BW Series

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Pin No.	Pin name	Circuit type	Function
53	D1VP	USBDREV	USB down port 1 + pin
54	D1VM	USBDREV	USB down port 1 – pin
55	D2VP	USBDREV	USB down port 2 + pin
56	D2VM	USBDREV	USB down port 2 – pin
57	D3VP	USBDREV	USB down port 3 + pin
58	D3VM	USBDREV	USB down port 3 – pin
59	D4VP	USBDREV	USB down port 4 + pin
60	D4VM	USBDREV	USB down port 4 – pin
61	P40/POW1	B	General-purpose CMOS I/O pin. This pin also serves as a USB Down Port power control signal pin.
62	P41/POW2	B	General-purpose CMOS I/O pin. This pin also serves as a USB Down Port power control signal pin.
63	P42/POW3	B	General-purpose CMOS I/O pin. This pin also serves as a USB Down Port power control signal pin.
64	P43/POW4	B	General-purpose CMOS I/O pin. This pin also serves as a USB Down Port power control signal pin.

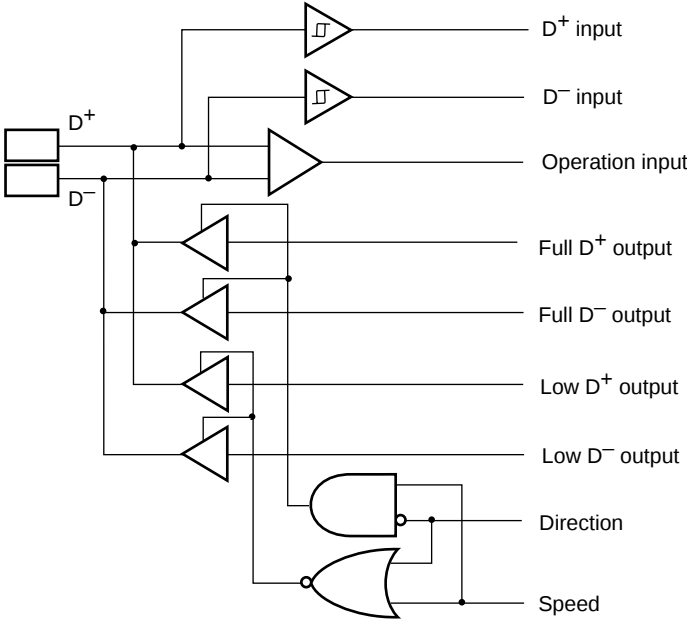
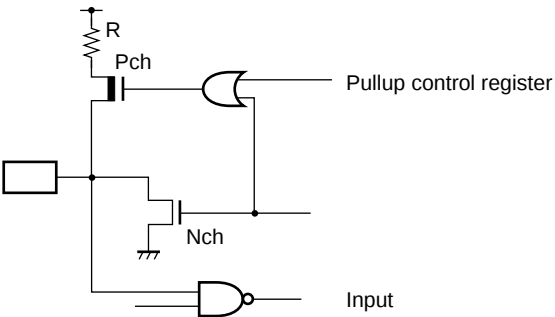
■ I/O CIRCUIT TYPE

Type	Circuit	Remarks
A		Oscillation feedback resistance Approx. 1 MΩ
B		CMOS I/O
E		CMOS I/O Hysteresis input
F		CMOS input
I		Hysteresis I/O Pullup resistance

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Type	Circuit	Remarks
USBDV	 D⁺ input D⁻ input Operation input Full D⁺ output Full D⁻ output Low D⁺ output Low D⁻ output Direction Speed	USB I/O
K	 Pullup control register Input	Nch open drain I/O

■ HANDLING DEVICES

1. Preventing Latchup

Latchup may occur on CMOS ICs if voltage higher than V_{CC} or lower than V_{SS} is applied to input or output pins other than the medium- and high-voltage pins or if voltage higher than the rating is applied between V_{CC} and V_{SS} .

When latchup occurs, power supply current increases rapidly and might thermally damage elements. When using, take great care not to exceed the absolute maximum ratings.

Also take care to prevent the analog input from exceeding the digital power supply (V_{CC}) when the power supply to the analog power system is turned on and off.

2. Treatment of Unused Input Pins

Leaving unused input pins open could cause malfunctions and latchup leading to permanent damage to the pins. These unused pins should be connected to a pullup or pulldown resistance of at least $2\text{ k}\Omega$ between the pin and the power supply.

Unused I/O pins should be placed in output state to leave it open or pins that are in input state should be handled the same as unused input pins.

3. Power Supply Voltage Fluctuations

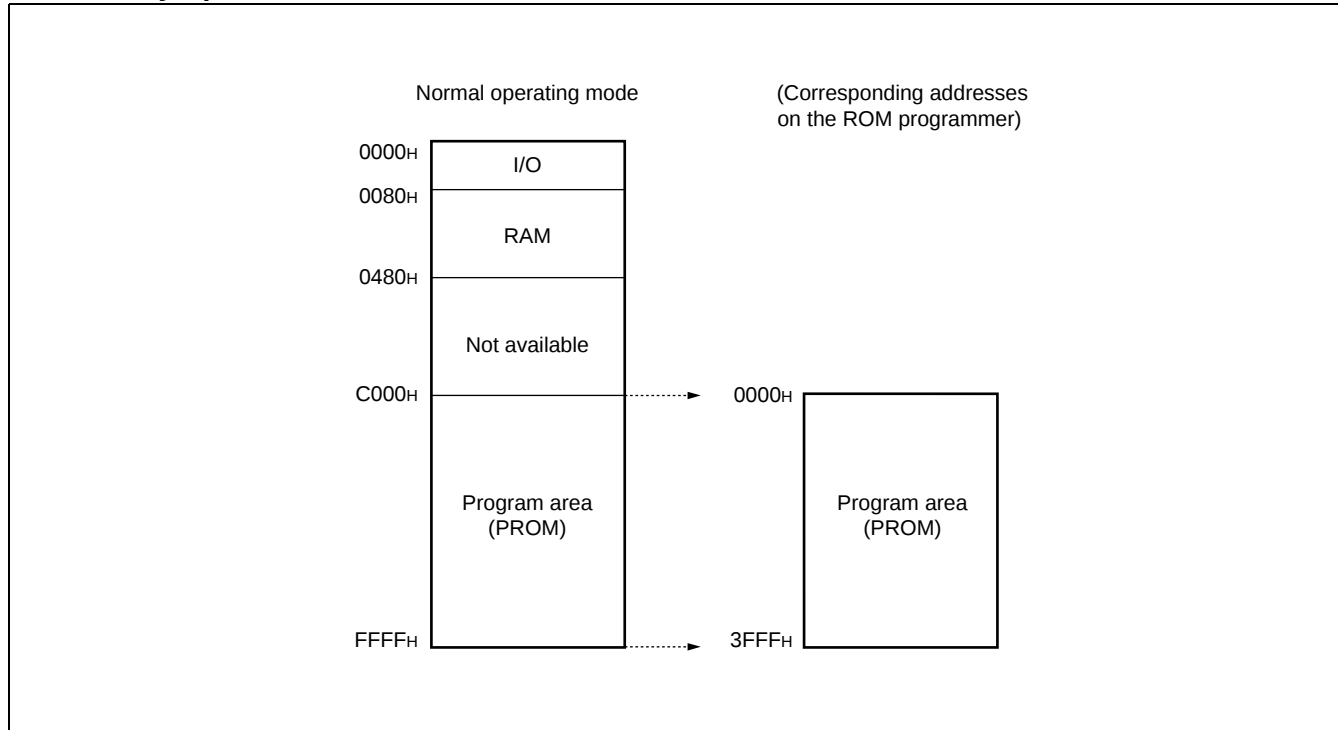
Although V_{CC} power supply voltage is assured to operate within the rated range, a rapid fluctuation of the voltage could cause malfunctions even if it occurs within the rated range. Stabilizing voltage supplied to the IC is therefore important. As stabilization guidelines, it is recommended to control power so that V_{CC} ripple fluctuations (P-P value) will be less than 10% of the standard V_{CC} value at the commercial frequency (50 to 60 Hz) and the transient fluctuation rate will be less than 0.1 V/ms at the time of a momentary fluctuation such as when power is switched.

MB89590B/BW Series

■ ONE-TIME PROM AND EPROM MICROCONTROLLER PROGRAMMING SPECIFICATIONS

PROM mode is available on the MB89P595B/BW microcontrollers. The use of a dedicated adapter allows you to program the devices with a general-purpose ROM programmer. However, keep in mind that electronic signature mode is not available.

1. Memory Space



2. ROM programmer adapter and its compatible programmers

Package	Compatible adapter	Compatible programmers and models
	Sun Hayato Co, Ltd.	Ando Denki K. K.
FTP-64P-M03	ROM2-64LQF-32DP-8LA	AF9708 (Version 1.40 or higher) AF9709 (Version 1.40 or higher) AF9723 (Version 1.50 or higher)

Inquiry:

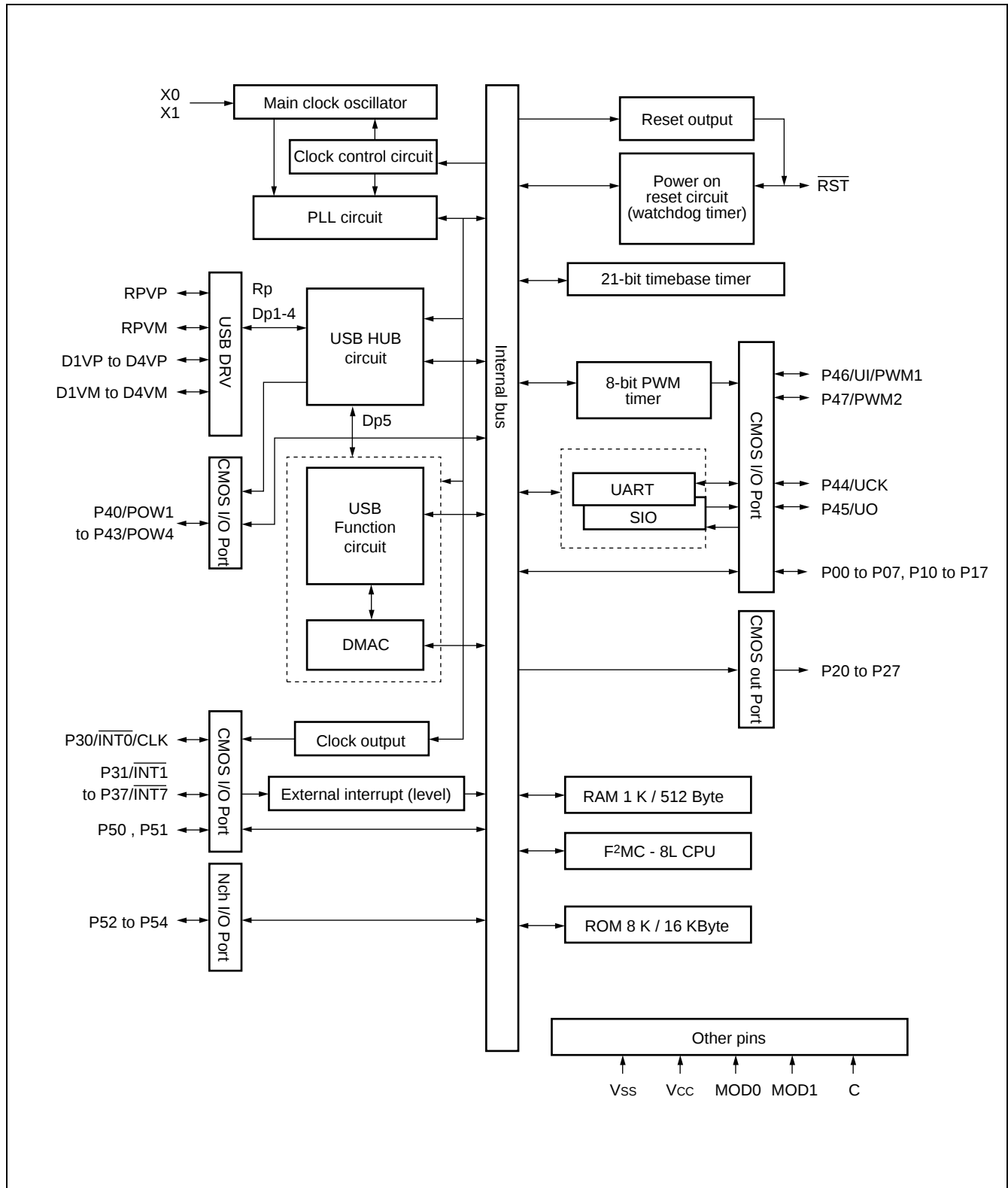
Sun Hayato Co., Ltd. : TEL. 81-3-3986-0403

Ando Denki K. K. : TEL. 81-3-3733-1160

3. Programming the EPROM (Using the Ando Denki K.K. programmer)

- (1) Set the EPROM programmer type code to 17209.
- (2) Load program data on to the EPROM programmer at 0000H to 3FFFH.
- (3) Program C000H to FFFFH with the EPROM programmer.

■ BLOCK DIAGRAM



MB89590B/BW Series

■ CPU CORE

1. Memory Space

The MB89590B/BW microcontrollers offer a memory space of 64 Kbytes consisting of the I/O, RAM and ROM areas. The memory space contains areas that are used for specific purposes, such as a general-purpose register and a vector table.

- I/O area (addresses : 0000_H through 007F_H)

This area is assigned with the control and data registers, for example, of peripheral functions to be built in. The I/O area is as accessible as the memory since the area is assigned to a part of the memory space. Direct addressing also allows the area to be accessed faster.

- RAM area

As an internal data area, a static RAM is built in.

The internal RAM capacity varies with the product type.

The area 80_H to FF_H can be accessed at high speed with direct addressing.

The area 100_H to 1FF_H can be used a general-purpose register area. (The usable area is limited depending on the product.)

When reset, RAM data becomes undefined.

- ROM area

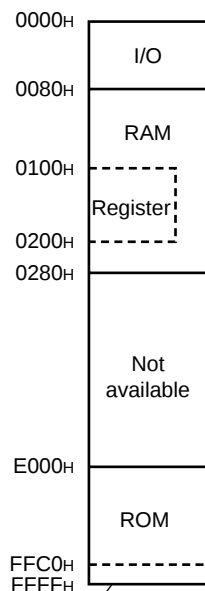
As an internal program area, a ROM is built in.

The internal ROM capacity varies with the product type.

The area FFC0_H to FFFF_H should be used for a vector table, for example.

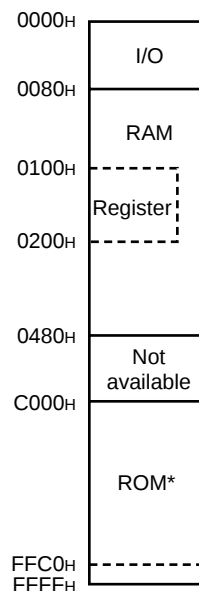
- Memory Map

MB89593B
MB89593BW



Vector table
(reset, interrupt, vector call instructions)

MB89P595B, MB89P595BW
MB89595B, MB89595BW



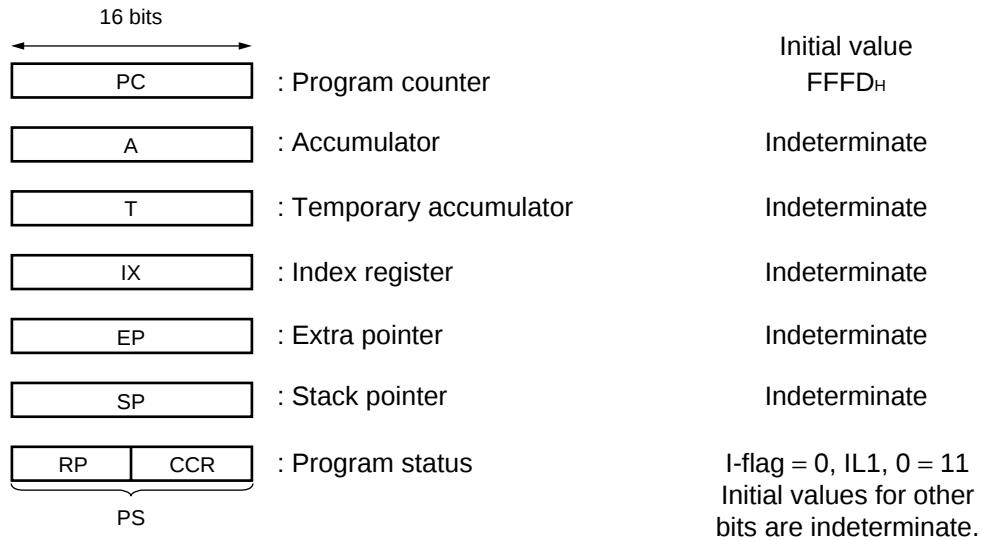
* The area is EPROM on the MB89P595B and MB89P595BW microcontrollers.

2. Registers

The MB89590B/BW series has two types of registers; the registers dedicated to specific purposes in the CPU and the general-purpose registers.

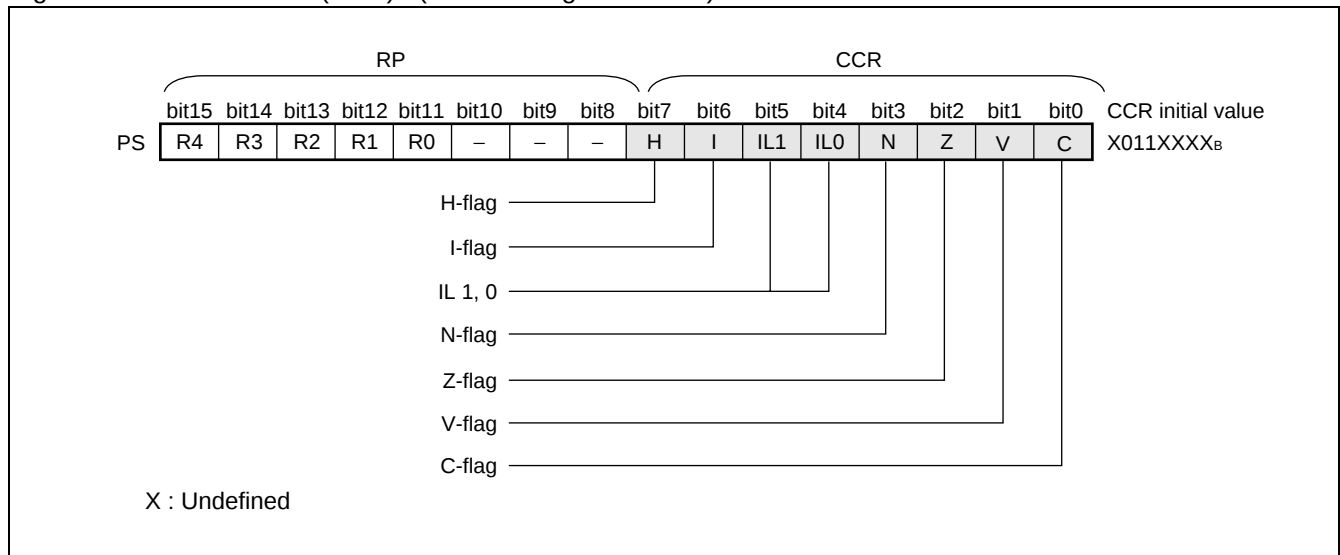
The dedicated registers are as follows:

- Program counter (PC) : A 16-bit register to indicate locations where instructions are stored.
- Accumulator (A) : A 16-bit register for temporary storage of operations. In the case of an 8-bit data processing instruction, the lower one byte is used.
- Temporary accumulator (T) : A 16-bit register which performs operations with the accumulator. In the case of an 8-bit data processing instruction, the lower one byte is used.
- Index register (IX) : A 16-bit register for index modification.
- Extra pointer (EP) : A 16-bit register to point to a memory address.
- Stack pointer (SP) : A 16-bit register to indicate a stack area.
- Program status (PS) : A 16-bit register to store a register pointer or a condition code.



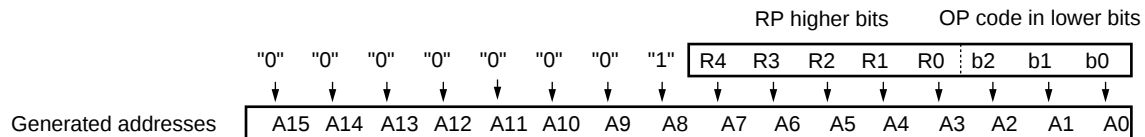
MB89590B/BW Series

The PS register can further be divided into the register bank pointer in the higher 8 bits (RP) and the condition code register in the lower 8 bits (CCR) . (See the diagram below.)



The RP points to the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule shown next.

Rule for Conversion of Actual Addresses in the General-purpose Register Area



The CCR consists of the bits indicating arithmetic operation results or transfer data contents and the bits that control CPU operations at the time of an interrupt.

- H flag : The flag is set to "1" when an arithmetic operation results in a carry from bit 3 to bit 4 or in a borrow from bit 4 to bit 3. The bit is cleared to "0" in other instances. The flag is for decimal adjustment instructions; do not use for other than additions and subtractions.
- I flag : Interrupt is enabled when this flag is set to "1." Interrupt is disabled when this flag is set to "0." The flag is set to "0" when reset.
- IL1, 0 : Indicates the level of the interrupt currently enabled. An interrupt is processed only if its level is higher than the value this bit indicates.

IL1	IL0	Interrupt level	High-low
0	0	1	Higher ↑ ↓ Lower = no interruption
0	1		
1	0	2	
1	1	3	

- N flag : The flag is set to "1" when an arithmetic operation results in setting of the MSB to "1" or is cleared to "0" when the MSB is set to "1."
- Z flag : The flag is set to "1" when an arithmetic operation results in "0" or is set to "0" in other instances.
- V flag : The flag is set to "1" when an arithmetic operation results in two's complement overflow or is cleared to "0" if no overflow occurs.
- C flag : The flag is set to "1" when an arithmetic operation results in a carry from bit 7 or in a borrow to bit 7. The flag is cleared to "0" if neither of them occurs. In the case of a shift instruction, the flag is set to the shift-out value.

The following general-purpose registers are provided:

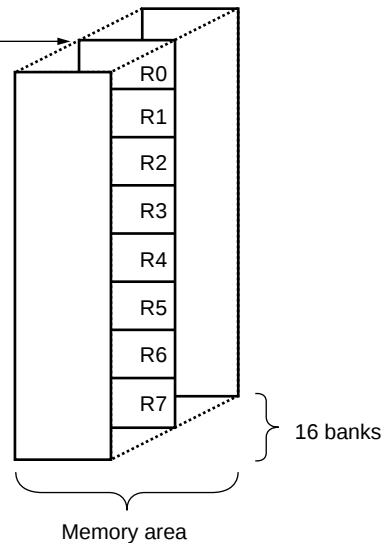
General-purpose registers : 8-bit data storage registers

The general-purpose registers are 8 bits in length and located in the register banks in the memory. One bank contains eight registers and the MB89590B/BW microcontrollers allow a total of 16 banks to be used at maximum.

The bank currently in use is indicated by the register bank pointer (RP) .

Register Bank Configuration

This address = $0100_H + 8 \times (RP)$



MB89590B/BW Series

■ I/O MAP

Address	Register name	Register description	Read/write	Initial value
00 _H	PDR0	Port 0 data register	R/W	XXXXXXXX
01 _H	DDR0	Port 0 direction register	W	00000000
02 _H	PDR1	Port 1 data register	R/W	XXXXXXXX
03 _H	DDR1	Port 1 direction register	W	00000000
04 _H	PDR2	Port 2 data register	R/W	00000000
05 _H	Vacancy			
06 _H	Vacancy			
07 _H	SYCC	System clock control register	R/W	XXX11X00
08 _H	STBC	Standby control register	R/W	0001XXXX
09 _H	WDTC	Watchdog timer control register	R/W	0XXXXXXXX
0A _H	TBTC	Timebase timer control register	R/W	00XXX000
0B _H	Vacancy			
0C _H	PDR3	Port 3 data register	R/W	XXXXXXXX
0D _H	DDR3	Port 3 direction register	R/W	00000000
0E _H	Vacancy			
0F _H	Vacancy			
10 _H	PDR4	Port 4 data register	R/W	XXXXXXXX
11 _H	DDR4	Port 4 direction register	R/W	00000000
12 _H	PDR5	Port 5 data register	R/W	XXX111XX
13 _H	DDR5	Port 5 direction register	R/W	XXXXXX00
14 _H to 20 _H	Vacancy			
21 _H	PURR0	Port 0 pullup option setting register	R/W	11111111
22 _H	PURR1	Port 1 pullup option setting register	R/W	11111111
23 _H	PURR2	Port 2 pullup option setting register	R/W	11111111
24 _H	PURR3	Port 3 pullup option setting register	R/W	11111111
25 _H	PURR4	Port 4 pullup option setting register	R/W	11111111
26 _H	PURR5	Port 5 pullup option setting register	R/W	XXX11111
27 _H	CTR1	PWM control register 1	R/W	00000000
28 _H	CTR2	PWM control register 2	R/W	000X0000
29 _H	CTR3	PWM control register 3	R/W	X000XXXX
2A _H	CMR1	PWM compare register 1	W	XXXXXXXX
2B _H	CMR2	PWM compare register 2	W	XXXXXXXX
2C _H	CKR	Clock output control register	R/W	XXXXXXXX0

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Address	Register name	Register description	Read/write	Initial value
2D _H	SCS	Serial clock switching register	R/W	XXXXXXXX 0
2E _H	Vacancy			
2F _H	SMC1	Serial mode control register 1	R/W	00000000
30 _H	SMC2	Serial mode control register 2	R/W	00000000
31 _H	SSD	Serial status and control register	R	00001XXX
32 _H	SIDR/SODR	Serial input/serial output data register	R/W	XXXXXXXX
33 _H	SRC	Serial rate control register	R/W	XXXXXXXX
34 _H to 3B _H	Vacancy			
3C _H	EIE	External interrupt control register	R/W	00000000
3D _H	EIF	External interrupt flag register	R/W	XXXXXXXX 0
3E _H	Vacancy			
3F _H	Vacancy			
40 _H	HMDR	HUB mode register	R/W	10XXXXXX
41 _H	HDSR1	Hub descriptor register 1	R/W	XXXXXXXX
42 _H	HDSR2	Hub descriptor register 2	R/W	XXXXXXXX
43 _H	HDSR3	Hub descriptor register 3	R/W	XXXXXXXX
44 _H	HSTR	Hub status register	R/W	00000000
45 _H	OCCR	Overcurrent register	R/W	0XXX0000
46 _H	DADR	Descriptor ROM address register	R/W	XXXXXXXX
47 _H	SDSR	String 0 descriptor select register	R/W	XXXXX000
48 _H to 4F _H	Vacancy			
50 _H	UMDR	USB reset mode register	R/W	1000XX00
51 _H	DBAR	DMA base address register	R/W	XXXXXXXX
52 _H	TDCR0	Transfer data count register 0	R/W	X0000000
53 _H	TDCR1	Transfer data count register 1	R/W	X0000000
54 _H	Vacancy			
55 _H	TDCR21	Transfer data count register 2	R/W	X0000000
56 _H	Vacancy			
57 _H	TDCR3	Transfer data count register 3	R/W	X0000000
58 _H	UCTR	USB control register	R/W	00000000
59 _H	USTR1	USB status register 1	R/W	00000000
5A _H	USTR2	USB status register 2	R	XXXXXX00

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MB89590B/BW Series

(Continued)

Address	Register name	Register description	Read/write	Initial value
5B _H	UMSKR	USB interrupt mask register	R/W	00000000
5C _H	UFRMR1	USB frame status register 1	R	XXXXXXXX
5D _H	UFRMR2	USB frame status register 2	R	XXXXXXXX
5E _H	EPER	USB endpoint enable register	R/W	XXXX0001
5F _H	EPBR0	Endpoint setup register 0	R/W	X0000000
60 _H	EPBR11	Endpoint setup register 11	R/W	XX0000XX
61 _H	EPBR12	Endpoint setup register 12	R/W	X0000000
62 _H	EPBR21	Endpoint setup register 21	R/W	XX0000XX
63 _H	EPBR22	Endpoint setup register 22	R/W	X0000000
64 _H	EPBR31	Endpoint setup register 31	R/W	XX0000XX
65 _H	EPBR32	Endpoint setup register 32	R/W	X0000000
66 _H to 7B _H	Vacancy			
7C _H	ILR1	Interrupt level setting register 1	W	11111111
7D _H	ILR2	Interrupt level setting register 2	W	11111111
7E _H	ILR3	Interrupt level setting register 3	W	11111111
7F _H	Vacancy			
• Information about read/write R/W : Read or write enabled, R : Read only, W : Write only • Information about initial values 0 : The initial value of this bit is “0.” 1 : The initial bit of this bit is “1.” X : The initial value of this bit is undefined.				

Note : Vacancies are not for use.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

($V_{SS} = 0\text{ V}$)

Parameter	Symbol	Value		Unit	Remarks
		Min.	Max.		
Power supply voltage	V_{CC}	$V_{SS} - 0.3$	$V_{SS} + 6.0$	V	
Input voltage	V_I	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V	
Output voltage	V_O	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V	
"L" level average output current	I_{OLAV}	—	4	mA	Average value (operating current $\times$ operating rate)
"L" level total maximum output current	ΣI_{OL}	—	100	mA	
"L" level total average output current	ΣI_{OLAV}	—	40	mA	Average value (operating current $\times$ operating rate)
"H" level maximum output current	I_{OH}	—	-15	mA	
"H" level average output current	I_{OHAV}	—	-4	mA	Average value (operating current $\times$ operating rate)
"H" level total maximum output current	ΣI_{OH}	—	-50	mA	
"H" level total average output current	ΣI_{OHAV}	—	-20	mA	Average value (operating current $\times$ operating rate)
Power consumption	P_D	—	300	mW	
Operating temperature	T_A	-40	+85	°C	
Storage temperature	T_{stg}	-55	+150	°C	

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

MB89590B/BW Series

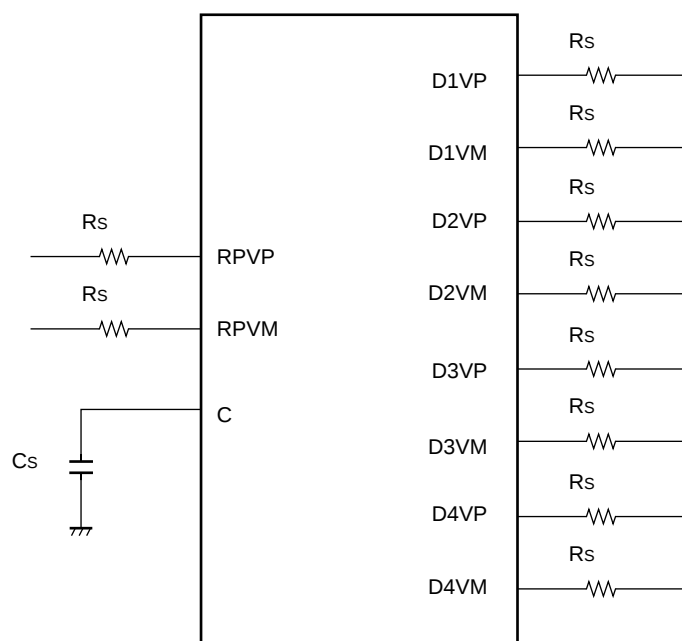
2. Recommended Operating Conditions

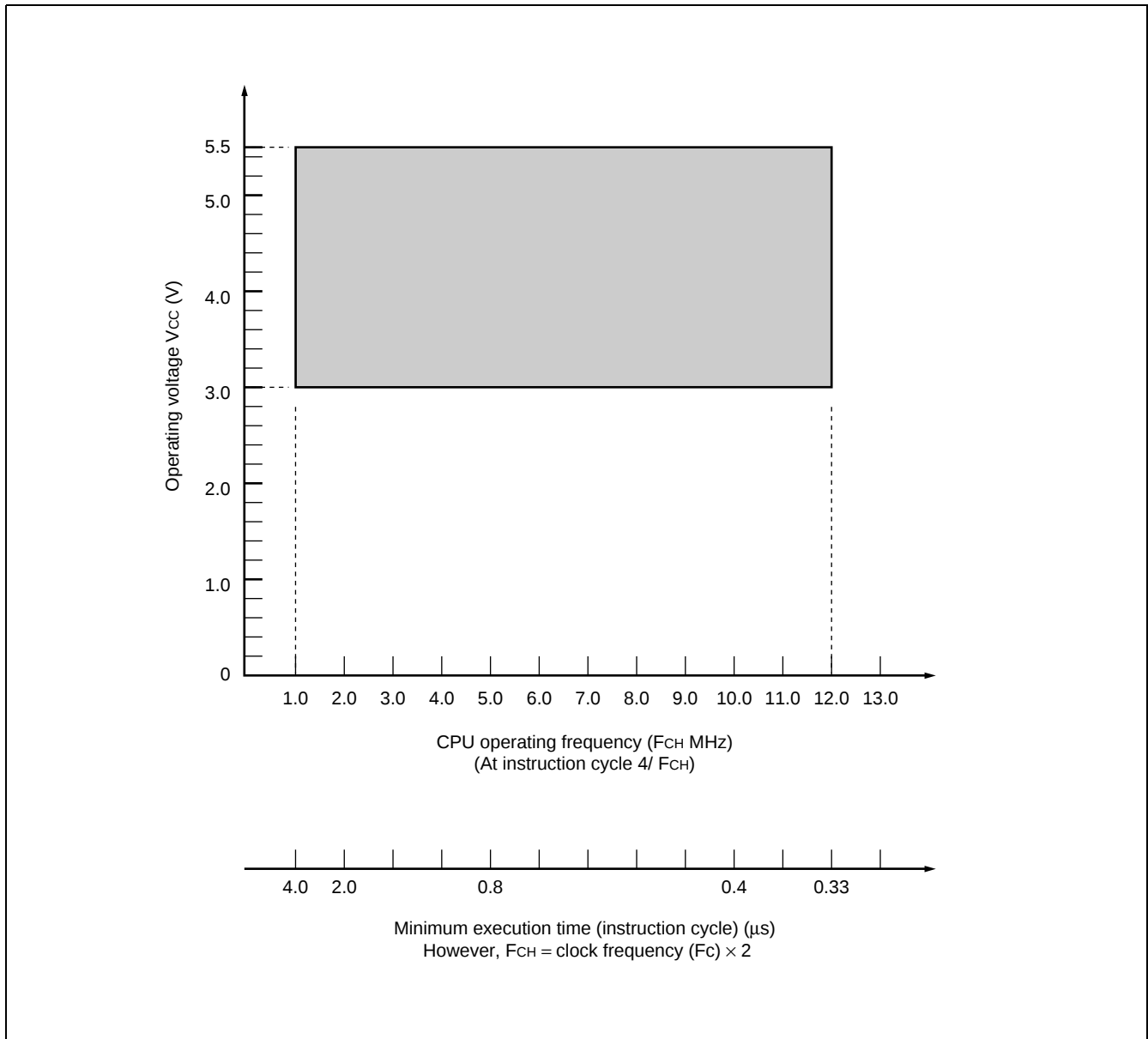
($V_{SS} = 0\text{ V}$)

Parameter	Symbol	Value			Unit	Remarks
		Min.	Typ.	Max.		
Power supply voltage	V_{CC}	3.0	—	5.5	V	
Operating temperature	T_A	-40	—	+85	°C	
Smoothing capacitor	C_S	0.1	—	1.0	μF	at $V_{CC} = 5.0\text{ V}^*$
Series resistance	R_S	—	16	—	Ω	When the USB function is in use

* : Use either a ceramic capacitor or a capacitor with similar frequency characteristics. The capacity of the smoothing capacitor for the V_{CC} pin should be greater than that of the C_S . When using with a supply voltage of 3.3 V, connect pin C with V_{CC} to input 3.3 V.

• C and USB Port Pin Connection Diagram





WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

MB89590B/BW Series

3. DC Characteristics

($V_{CC} = 5.0\text{ V}$, $V_{SS} = 0\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
“H” level input voltage	V_{IH}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P54, MOD0, MOD1	—	$0.7 V_{CC}$	—	$V_{CC} + 0.3$	V	
	V_{IHS}	$\overline{RST}$, $\overline{INT0}$ to $\overline{INT7}$, UCK, UI	—	$0.8 V_{CC}$	—	$V_{CC} + 0.3$	V	
“L” level input voltage	V_{IL}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P54, MOD0, MOD1	—	$V_{SS} - 0.3$	—	$0.3 V_{CC}$	V	
	V_{ILS}	$\overline{RST}$, $\overline{INT0}$ to $\overline{INT7}$, UCK, UI	—	$V_{SS} - 0.3$	—	$0.2 V_{CC}$	V	
Open-drain output application voltage	V_{D1}	P52 to P54	—	$V_{SS} - 0.3$	—	$V_{CC} + 0.3$	V	
“H” level output voltage	V_{OH}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50, P51	$I_{OH} = -2.0\text{ mA}$	4.0	—	—	V	
“L” level output voltage	V_{OL}	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40 to P47, P50 to P54, $\overline{RST}$	$I_{OL} = 4.0\text{ mA}$	—	—	0.4	V	
Input leakage current (Hi-Z output leakage current)	I_{LI}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50, P51	$0.0 < V_I < V_{CC}$	-5	—	+5	μA	When no pul-lup resistance is specified

(Continued)

MB89590B/BW Series

(Continued)

($V_{CC} = 5.0 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_A = -40 \text{ }^{\circ}\text{C}$ to $+85 \text{ }^{\circ}\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Open-drain output leakage current	$I_{L\text{IOD}}$	P52 to P54	$0.0 < V_I < V_{SS} + 5.5$	—	—	+5	μA	
Pullup resistance	R_{PULL}	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P54, $\overline{\text{RST}}$	$V_I = 0.0 \text{ V}$	25	50	100	$\text{k}\Omega$	$\overline{\text{RST}}$ is excluded when pullup resistance available is specified.
Power supply current	I_{CC}	V_{CC}	$F_{\text{CH}} = 12.0 \text{ MHz}$ $V_{\text{CC}} = 5.0 \text{ V}$ $t_{\text{inst}} = 0.333 \mu\text{s}$	—	25	38	mA	MB89P595B/ BW MB89595B/ BW
	I_{CCS1}		$F_{\text{CH}} = 12.0 \text{ MHz}$ $V_{\text{CC}} = 5.0 \text{ V}$ $t_{\text{inst}} = 0.333 \mu\text{s}$	—	20	30	mA	Sleep mode
	I_{CCH}		$T_A = 25 \text{ }^{\circ}\text{C}$	—	5	20	μA	Stop
Input capacitance	C_{IN}	Other than V_{CC} and V_{SS}	$f = 1 \text{ MHz}$	—	10	—	pF	

MB89590B/BW Series

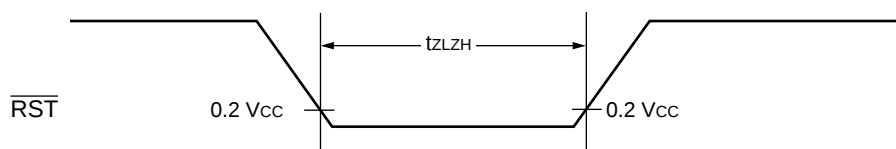
4. AC Characteristics

(1) Reset Timing

($V_{CC} = 5.0 \text{ V}$, $V_{SS} = 0 \text{ V}$, $T_A = -40 \text{ }^{\circ}\text{C}$ to $+85 \text{ }^{\circ}\text{C}$)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min.	Max.		
$\overline{\text{RST}}$ "L" pulse width	t_{ZLZH}	—	$16 t_{HCLY}$	—	ns	

Note : t_{HCLY} is the internal main clock oscillating cycle ($1/2 F_c$) .

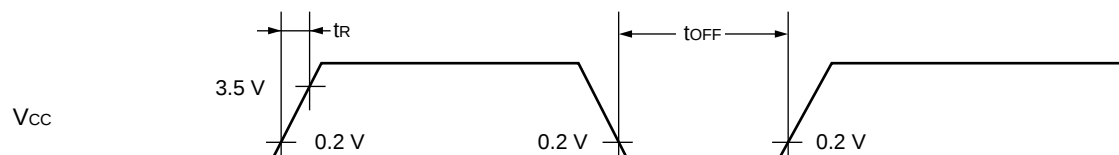


(2) Power-on Reset

($V_{SS} = 0 \text{ V}$, $T_A = -40 \text{ }^{\circ}\text{C}$ to $+85 \text{ }^{\circ}\text{C}$)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min.	Max.		
Power supply rising time	t_R	—	0.066	50	ms	
Power supply cutoff time	t_{OFF}	—	4	—	ns	Due to repeated operations

Note : The power supply must be up within the selected oscillation stabilization time. When the supply voltage needs to be varied while operating, it is recommended to smoothly start up the voltage.

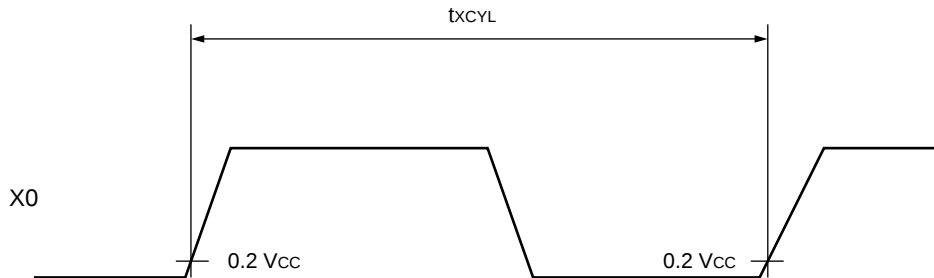


(3) Clock Timing

($V_{SS} = 0\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$)

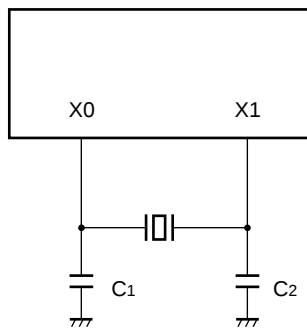
Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Clock frequency	F_C	X0, X1	—	—	6	—	MHz	
Clock cycle time	t_{XCYL}	X0, X1		—	166.6	—	ns	
Internal main clock frequency	F_{CH}	—		—	12	—	MHz	Twice the F_C
Internal clock cycle	t_{HCYL}	—		—	83.3	—	ns	$t_{XCYL}/2$

• X0 and X1 Timing and Conditions



• Clock Conditions

When a crystal resonator is used



(4) Instruction Cycle

($V_{SS} = 0\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Value	Unit	Remarks
Instruction cycle (Min. execution time)	t_{inst}	$4 / F_{CH}$, $8 / F_{CH}$, $16 / F_{CH}$, $64 / F_{CH}$	μs	When operating at $F_{CH} = 12\text{ MHz}$ $t_{inst} = 0.33\text{ }\mu\text{s}$ ($4 / F_{CH}$)

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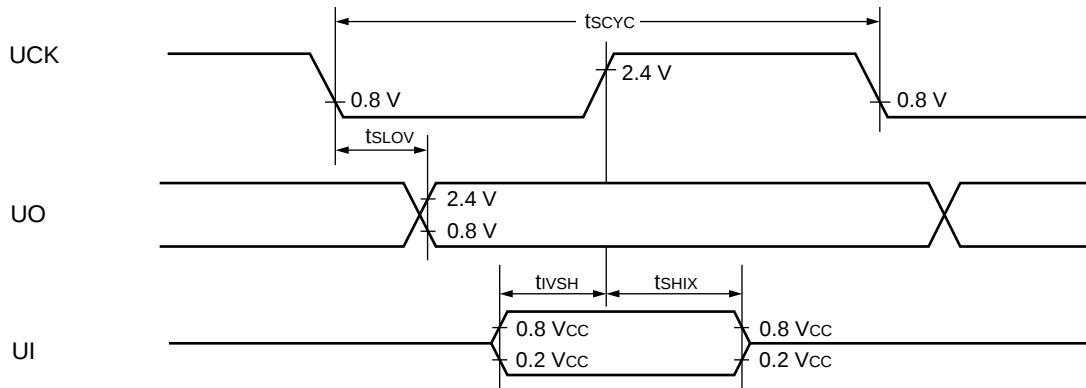
(5) UART Serial I/O Timing

($V_{CC} = 5.0\text{ V}$, $V_{SS} = 0\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$)

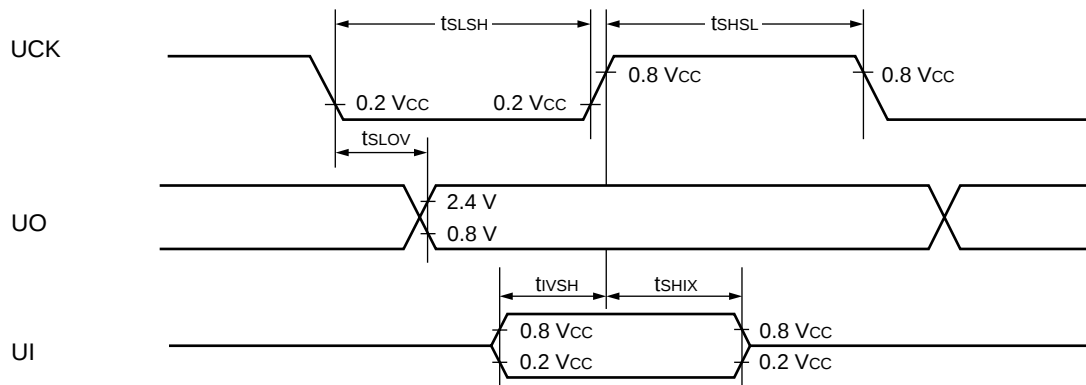
Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
				Min.	Max.		
Serial clock cycle time	t_{SCYC}	UCK	Internal shift clock mode	$2\ t_{inst}^*$	—	μs	
UCK $\downarrow \rightarrow$ UO	t_{SLOV}	UCK, UO		-200	200	ns	
Valid UI $\rightarrow$ UCK $\uparrow$	t_{IVSH}	UI, UCK		200	—	ns	
UCK $\uparrow \rightarrow$ Rvalid UI hold time	t_{SHIX}	UCK, UI		200	—	ns	
Serial clock "H" pulse width	t_{SHSL}	UCK	External shift clock mode	$1\ t_{inst}^*$	—	μs	
Serial clock "L" pulse width	t_{SLSH}			$1\ t_{inst}^*$	—	μs	
UCK $\downarrow \rightarrow$ UO time	t_{SLOV}	UCK, UO		0	200	ns	
Valid UI $\rightarrow$ UCK $\uparrow$	t_{IVSH}	UI, UCK		200	—	ns	
UCK $\uparrow \rightarrow$ Rvalid UI hold time	t_{SHIX}	UCK, UI		200	—	ns	

* : For information about t_{inst} see "Instruction Cycle."

• Internal shift clock mode



• External shift clock mode

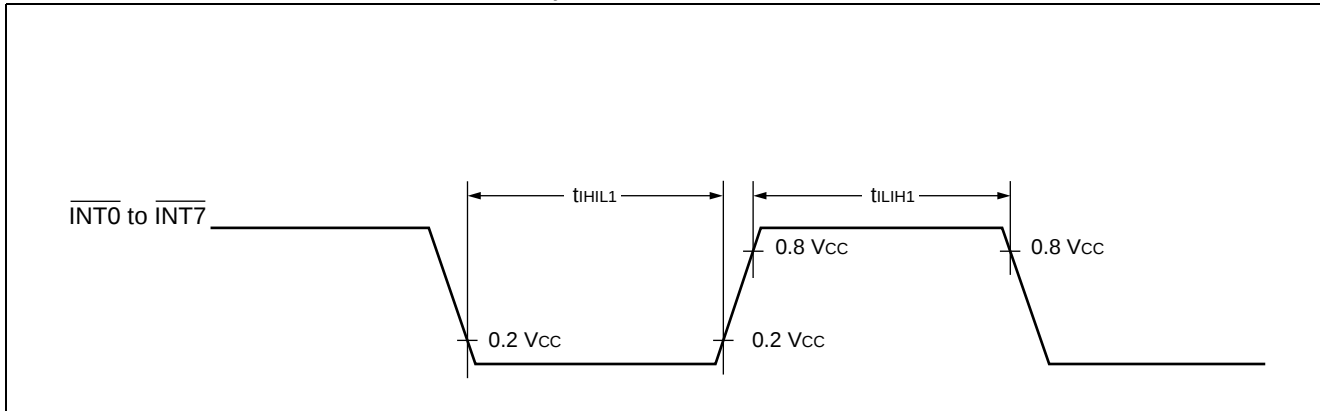


(6) Peripheral Input Timing

($V_{CC} = 5.0\text{ V}$, $V_{SS} = 0\text{ V}$, $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$)

Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
				Min.	Max.		
Peripheral input "H" pulse width 1	$t_{\text{LH}1}$	$\overline{\text{INT0}}$ to $\overline{\text{INT7}}$	—	$2\ t_{\text{inst}}^*$	—	μs	
Peripheral input "L" pulse width 1	$t_{\text{HL}1}$		—	$2\ t_{\text{inst}}^*$	—	μs	

* : For information about t_{inst} , see "Instruction Cycle."



MB89590B/BW Series

■ INSTRUCTIONS (136 INSTRUCTIONS)

Execution instructions can be divided into the following four groups:

- Transfer
- Arithmetic operation
- Branch
- Others

Table 1 lists symbols used for notation of instructions.

Table 1 Instruction Symbols

Symbol	Meaning
dir	Direct address (8 bits)
off	Offset (8 bits)
ext	Extended address (16 bits)
#vct	Vector table number (3 bits)
#d8	Immediate data (8 bits)
#d16	Immediate data (16 bits)
dir: b	Bit direct address (8:3 bits)
rel	Branch relative address (8 bits)
@	Register indirect (Example: @A, @IX, @EP)
A	Accumulator A (Whether its length is 8 or 16 bits is determined by the instruction in use.)
AH	Upper 8 bits of accumulator A (8 bits)
AL	Lower 8 bits of accumulator A (8 bits)
T	Temporary accumulator T (Whether its length is 8 or 16 bits is determined by the instruction in use.)
TH	Upper 8 bits of temporary accumulator T (8 bits)
TL	Lower 8 bits of temporary accumulator T (8 bits)
IX	Index register IX (16 bits)
EP	Extra pointer EP (16 bits)
PC	Program counter PC (16 bits)
SP	Stack pointer SP (16 bits)
PS	Program status PS (16 bits)
dr	Accumulator A or index register IX (16 bits)
CCR	Condition code register CCR (8 bits)
RP	Register bank pointer RP (5 bits)
Ri	General-purpose register Ri (8 bits, i = 0 to 7)
×	Indicates that the very × is the immediate data. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
(×)	Indicates that the contents of × is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)
((×))	The address indicated by the contents of × is the target of accessing. (Whether its length is 8 or 16 bits is determined by the instruction in use.)

Columns indicate the following:

Mnemonic: Assembler notation of an instruction

~: The number of instructions

#: The number of bytes

Operation: Operation of an instruction

TL, TH, AH: A content change when each of the TL, TH, and AH instructions is executed. Symbols in the column indicate the following:

- “—” indicates no change.
- dH is the 8 upper bits of operation description data.
- AL and AH must become the contents of AL and AH prior to the instruction executed.
- 00 becomes 00.

N, Z, V, C: An instruction of which the corresponding flag will change. If + is written in this column, the relevant instruction will change its corresponding flag.

OP code: Code of an instruction. If an instruction is more than one code, it is written according to the following rule:
Example: 48 to 4F ← This indicates 48, 49, ... 4F.

Table 2 Transfer Instructions (48 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
MOV dir,A	3	2	(dir) ← (A)	—	—	—	-----	45
MOV @IX +off,A	4	2	((IX) +off) ← (A)	—	—	—	-----	46
MOV ext,A	4	3	(ext) ← (A)	—	—	—	-----	61
MOV @EP,A	3	1	((EP)) ← (A)	—	—	—	-----	47
MOV Ri,A	3	1	(Ri) ← (A)	—	—	—	-----	48 to 4F
MOV A,#d8	2	2	(A) ← d8	AL	—	—	++--	04
MOV A,dir	3	2	(A) ← (dir)	AL	—	—	++--	05
MOV A,@IX +off	4	2	(A) ← ((IX) +off)	AL	—	—	++--	06
MOV A,ext	4	3	(A) ← (ext)	AL	—	—	++--	60
MOV A,@A	3	1	(A) ← ((A))	AL	—	—	++--	92
MOV A,@EP	3	1	(A) ← ((EP))	AL	—	—	++--	07
MOV A,Ri	3	1	(A) ← (Ri)	AL	—	—	++--	08 to 0F
MOV dir,#d8	4	3	(dir) ← d8	—	—	—	-----	85
MOV @IX +off,#d8	5	3	((IX) +off) ← d8	—	—	—	-----	86
MOV @EP,#d8	4	2	((EP)) ← d8	—	—	—	-----	87
MOV Ri,#d8	4	2	(Ri) ← d8	—	—	—	-----	88 to 8F
MOVW dir,A	4	2	(dir) ← (AH), (dir + 1) ← (AL)	—	—	—	-----	D5
MOVW @IX +off,A	5	2	((IX) +off) ← (AH), ((IX) +off + 1) ← (AL)	—	—	—	-----	D6
MOVW ext,A	5	3	(ext) ← (AH), (ext + 1) ← (AL)	—	—	—	-----	D4
MOVW @EP,A	4	1	((EP)) ← (AH), ((EP) + 1) ← (AL)	—	—	—	-----	D7
MOVW EP,A	2	1	(EP) ← (A)	—	—	—	-----	E3
MOVW A,#d16	3	3	(A) ← d16	AL	AH	dH	++--	E4
MOVW A,dir	4	2	(AH) ← (dir), (AL) ← (dir + 1)	AL	AH	dH	++--	C5
MOVW A,@IX +off	5	2	(AH) ← ((IX) +off), (AL) ← ((IX) +off + 1)	AL	AH	dH	++--	C6
MOVW A,ext	5	3	(AH) ← (ext), (AL) ← (ext + 1)	AL	AH	dH	++--	C4
MOVW A,@A	4	1	(AH) ← ((A)), (AL) ← ((A) + 1)	AL	AH	dH	++--	93
MOVW A,@EP	4	1	(AH) ← ((EP)), (AL) ← ((EP) + 1)	AL	AH	dH	++--	C7
MOVW A,EP	2	1	(A) ← (EP)	—	—	dH	-----	F3
MOVW EP,#d16	3	3	(EP) ← d16	—	—	—	-----	E7
MOVW IX,A	2	1	(IX) ← (A)	—	—	—	-----	E2
MOVW A,IX	2	1	(A) ← (IX)	—	—	dH	-----	F2
MOVW SP,A	2	1	(SP) ← (A)	—	—	—	-----	E1
MOVW A,SP	2	1	(A) ← (SP)	—	—	dH	-----	F1
MOV @A,T	3	1	((A)) ← (T)	—	—	—	-----	82
MOVW @A,T	4	1	((A)) ← (TH), ((A) + 1) ← (TL)	—	—	—	-----	83
MOVW IX,#d16	3	3	(IX) ← d16	—	—	—	-----	E6
MOVW A,PS	2	1	(A) ← (PS)	—	—	dH	-----	70
MOVW PS,A	2	1	(PS) ← (A)	—	—	—	++++	71
MOVW SP,#d16	3	3	(SP) ← d16	—	—	—	-----	E5
SWAP	2	1	(AH) ↔ (AL)	—	—	AL	-----	10
SETB dir: b	4	2	(dir): b ← 1	—	—	—	-----	A8 to AF
CLRB dir: b	4	2	(dir): b ← 0	—	—	—	-----	A0 to A7
XCH A,T	2	1	(AL) ↔ (TL)	AL	—	—	-----	42
XCHW A,T	3	1	(A) ↔ (T)	AL	AH	dH	-----	43
XCHW A,EP	3	1	(A) ↔ (EP)	—	—	dH	-----	F7
XCHW A,IX	3	1	(A) ↔ (IX)	—	—	dH	-----	F6
XCHW A,SP	3	1	(A) ↔ (SP)	—	—	dH	-----	F5
MOVW A,PC	2	1	(A) ← (PC)	—	—	dH	-----	F0

Note During byte transfer to A, T ← A is restricted to low bytes.

Operands in more than one operand instruction must be stored in the order in which their mnemonics are written. (Reverse arrangement of F²MC-8 family)

MB89590B/BW Series

Table 3 Arithmetic Operation Instructions (62 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
ADDC A,Ri	3	1	$(A) \leftarrow (A) + (Ri) + C$	—	—	—	++++	28 to 2F
ADDC A,#d8	2	2	$(A) \leftarrow (A) + d8 + C$	—	—	—	++++	24
ADDC A,dir	3	2	$(A) \leftarrow (A) + (dir) + C$	—	—	—	++++	25
ADDC A,@IX +off	4	2	$(A) \leftarrow (A) + ((IX) + off) + C$	—	—	—	++++	26
ADDC A,@EP	3	1	$(A) \leftarrow (A) + ((EP)) + C$	—	—	—	++++	27
ADDCW A	3	1	$(A) \leftarrow (A) + (T) + C$	—	—	dH	++++	23
ADDC A	2	1	$(AL) \leftarrow (AL) + (TL) + C$	—	—	—	++++	22
SUBC A,Ri	3	1	$(A) \leftarrow (A) - (Ri) - C$	—	—	—	++++	38 to 3F
SUBC A,#d8	2	2	$(A) \leftarrow (A) - d8 - C$	—	—	—	++++	34
SUBC A,dir	3	2	$(A) \leftarrow (A) - (dir) - C$	—	—	—	++++	35
SUBC A,@IX +off	4	2	$(A) \leftarrow (A) - ((IX) + off) - C$	—	—	—	++++	36
SUBC A,@EP	3	1	$(A) \leftarrow (A) - ((EP)) - C$	—	—	—	++++	37
SUBCW A	3	1	$(A) \leftarrow (T) - (A) - C$	—	—	dH	++++	33
SUBC A	2	1	$(AL) \leftarrow (TL) - (AL) - C$	—	—	—	++++	32
INC Ri	4	1	$(Ri) \leftarrow (Ri) + 1$	—	—	—	+++-	C8 to CF
INCW EP	3	1	$(EP) \leftarrow (EP) + 1$	—	—	—	----	C3
INCW IX	3	1	$(IX) \leftarrow (IX) + 1$	—	—	—	----	C2
INCW A	3	1	$(A) \leftarrow (A) + 1$	—	—	dH	++--	C0
DEC Ri	4	1	$(Ri) \leftarrow (Ri) - 1$	—	—	—	+++-	D8 to DF
DECW EP	3	1	$(EP) \leftarrow (EP) - 1$	—	—	—	----	D3
DECW IX	3	1	$(IX) \leftarrow (IX) - 1$	—	—	—	----	D2
DECW A	3	1	$(A) \leftarrow (A) - 1$	—	—	dH	++--	D0
MULU A	19	1	$(A) \leftarrow (AL) \times (TL)$	—	—	dH	----	01
DIVU A	21	1	$(A) \leftarrow (T) / (AL), MOD \rightarrow (T)$	dL	00	00	----	11
ANDW A	3	1	$(A) \leftarrow (A) \wedge (T)$	—	—	dH	++R—	63
ORW A	3	1	$(A) \leftarrow (A) \vee (T)$	—	—	dH	++R—	73
XORW A	3	1	$(A) \leftarrow (A) \nabla (T)$	—	—	dH	++R—	53
CMP A	2	1	$(TL) - (AL)$	—	—	—	++++	12
CMPW A	3	1	$(T) - (A)$	—	—	—	++++	13
RORC A	2	1	$\rightarrow C \rightarrow A \leftarrow$	—	—	—	++-+	03
ROLA A	2	1	$\leftarrow C \leftarrow A \leftarrow$	—	—	—	++-+	02
CMP A,#d8	2	2	$(A) - d8$	—	—	—	++++	14
CMP A,dir	3	2	$(A) - (dir)$	—	—	—	++++	15
CMP A,@EP	3	1	$(A) - ((EP))$	—	—	—	++++	17
CMP A,@IX +off	4	2	$(A) - ((IX) + off)$	—	—	—	++++	16
CMP A,Ri	3	1	$(A) - (Ri)$	—	—	—	++++	18 to 1F
DAA	2	1	Decimal adjust for addition	—	—	—	++++	84
DAS	2	1	Decimal adjust for subtraction	—	—	—	++++	94
XOR A	2	1	$(A) \leftarrow (AL) \nabla (TL)$	—	—	—	++R—	52
XOR A,#d8	2	2	$(A) \leftarrow (AL) \nabla d8$	—	—	—	++R—	54
XOR A,dir	3	2	$(A) \leftarrow (AL) \nabla (dir)$	—	—	—	++R—	55
XOR A,@EP	3	1	$(A) \leftarrow (AL) \nabla ((EP))$	—	—	—	++R—	57
XOR A,@IX +off	4	2	$(A) \leftarrow (AL) \nabla ((IX) + off)$	—	—	—	++R—	56
XOR A,Ri	3	1	$(A) \leftarrow (AL) \nabla (Ri)$	—	—	—	++R—	58 to 5F
AND A	2	1	$(A) \leftarrow (AL) \wedge (TL)$	—	—	—	++R—	62
AND A,#d8	2	2	$(A) \leftarrow (AL) \wedge d8$	—	—	—	++R—	64
AND A,dir	3	2	$(A) \leftarrow (AL) \wedge (dir)$	—	—	—	++R—	65

(Continued)

(Continued)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
AND A,@EP	3	1	$(A) \leftarrow (AL) \wedge (EP)$	—	—	—	++R—	67
AND A,@IX +off	4	2	$(A) \leftarrow (AL) \wedge ((IX) + off)$	—	—	—	++R—	66
AND A,Ri	3	1	$(A) \leftarrow (AL) \wedge (Ri)$	—	—	—	++R—	68 to 6F
OR A	2	1	$(A) \leftarrow (AL) \vee (TL)$	—	—	—	++R—	72
OR A,#d8	2	2	$(A) \leftarrow (AL) \vee d8$	—	—	—	++R—	74
OR A,dir	3	2	$(A) \leftarrow (AL) \vee (dir)$	—	—	—	++R—	75
OR A,@EP	3	1	$(A) \leftarrow (AL) \vee (EP)$	—	—	—	++R—	77
OR A,@IX +off	4	2	$(A) \leftarrow (AL) \vee ((IX) + off)$	—	—	—	++R—	76
OR A,Ri	3	1	$(A) \leftarrow (AL) \vee (Ri)$	—	—	—	++R—	78 to 7F
CMP dir,#d8	5	3	$(dir) - d8$	—	—	—	++++	95
CMP @EP,#d8	4	2	$((EP)) - d8$	—	—	—	++++	97
CMP @IX +off,#d8	5	3	$((IX) + off) - d8$	—	—	—	++++	96
CMP Ri,#d8	4	2	$(Ri) - d8$	—	—	—	++++	98 to 9F
INCW SP	3	1	$(SP) \leftarrow (SP) + 1$	—	—	—	----	C1
DECW SP	3	1	$(SP) \leftarrow (SP) - 1$	—	—	—	----	D1

Table 4 Branch Instructions (17 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
BZ/BEQ rel	3	2	If $Z = 1$ then $PC \leftarrow PC + rel$	—	—	—	----	FD
BNZ/BNE rel	3	2	If $Z = 0$ then $PC \leftarrow PC + rel$	—	—	—	----	FC
BC/BLO rel	3	2	If $C = 1$ then $PC \leftarrow PC + rel$	—	—	—	----	F9
BNC/BHS rel	3	2	If $C = 0$ then $PC \leftarrow PC + rel$	—	—	—	----	F8
BN rel	3	2	If $N = 1$ then $PC \leftarrow PC + rel$	—	—	—	----	FB
BP rel	3	2	If $N = 0$ then $PC \leftarrow PC + rel$	—	—	—	----	FA
BLT rel	3	2	If $V \vee N = 1$ then $PC \leftarrow PC + rel$	—	—	—	----	FF
BGE rel	3	2	If $V \vee N = 0$ then $PC \leftarrow PC + rel$	—	—	—	----	FE
BBC dir: b,rel	5	3	If $(dir: b) = 0$ then $PC \leftarrow PC + rel$	—	—	—	—+---	B0 to B7
BBS dir: b,rel	5	3	If $(dir: b) = 1$ then $PC \leftarrow PC + rel$	—	—	—	—+---	B8 to BF
JMP @A	2	1	$(PC) \leftarrow (A)$	—	—	—	----	E0
JMP ext	3	3	$(PC) \leftarrow ext$	—	—	—	----	21
CALLV #vct	6	1	Vector call	—	—	—	----	E8 to EF
CALL ext	6	3	Subroutine call	—	—	—	----	31
XCHW A,PC	3	1	$(PC) \leftarrow (A), (A) \leftarrow (PC) + 1$	—	—	dH	----	F4
RET	4	1	Return from subroutine	—	—	—	----	20
RETI	6	1	Return from interrupt	—	—	—	Restore	30

Table 5 Other Instructions (9 instructions)

Mnemonic	~	#	Operation	TL	TH	AH	NZVC	OP code
PUSHW A	4	1		—	—	—	----	40
POPW A	4	1		—	—	dH	----	50
PUSHW IX	4	1		—	—	—	----	41
POPW IX	4	1		—	—	—	----	51
NOP	1	1		—	—	—	----	00
CLRC	1	1		—	—	—	----R	81
SETC	1	1		—	—	—	----S	91
CLRI	1	1		—	—	—	----	80
SETI	1	1		—	—	—	----	90

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INSTRUCTION MAP

L	H	0	1	2	3	4	5	6	7	8	9	A	B	C	D	E	F
0		NOP	SWAP	RET	RETI	PUSHW A	POPW A	MOV A,ext	MOVW A,PS	CLRI	SETI	CLRB dir: 0	BBC dir: 0,rel	INCW A	DECW A	JMP @A	MOVW A,PC
1		MULU A	DIVU A	JMP addr16	CALL addr16	PUSHW IX	POPW IX	MOV ext,A	MOVW PS,A	CLRC	SETC	CLRB dir: 1	BBC dir: 1,rel	INCW SP	DECW SP	MOVW SPA	MOVW A,SP
2		ROL A	CMP A	ADDC A	SUBC A	XCH A,T	XOR A	AND A	OR A	MOV @A,T	MOV A,@A	CLRB dir: 2	BBC dir: 2,rel	INCW IX	DECW IX	MOVW IX,A	MOVW A,IX
3		ROR A	CMPW A	ADDCW A	SUBCW A	XCHW A,T	XORW A	ANDW A	ORW A	MOVW @A,T	MOVW A,@A	CLRB dir: 3	BBC dir: 3,rel	INCW EP	DECW EP	MOVW EPA	MOVW A,EP
4		MOV A,#d8	CMP A,#d8	ADDC A,#d8	SUBC A,#d8		XOR A,#d8	AND A,#d8	OR A,#d8	DAA	DAS	CLRB dir: 4	BBC dir: 4,rel	MOVW A,ext	MOVW ext,A	MOVW A,#d16	XCHW A,PC
5		MOV A,dir	CMP A,dir	ADDC A,dir	SUBC A,dir	MOV dir,A	XOR A,dir	AND A,dir	OR A,dir	MOV dir,#d8	CMP dir,#d8	CLRB dir: 5	BBC dir: 5,rel	MOVW A,dir	MOVW dir,A	XCHW A,SP	XCHW A,SP
6		MOV A,@IX+d	CMP A,@IX+d	ADDC A,@IX+d	SUBC A,@IX+d	MOV @IX+d,A	XOR A,@IX+d	AND A,@IX+d	OR A,@IX+d	MOV @IX+d,#d8	CMP @IX+d,#d8	CLRB dir: 6	BBC dir: 6,rel	MOVW A,@IX+d	MOVW @IX+d,A	XCHW IX,#d16	XCHW A,IX
7		MOV A,@EP	CMP A,@EP	ADDC A,@EP	SUBC A,@EP	MOV @EP,A	XOR A,@EP	AND A,@EP	OR A,@EP	MOV @EP,#d8	CMP @EP,#d8	CLRB dir: 7	BBC dir: 7,rel	MOVW A,@EP	MOVW @EP,A	XCHW EP,#d16	XCHW A,EP
8		MOV A,R0	CMP A,R0	ADDC A,R0	SUBC A,R0	MOV R0,A	XOR A,R0	AND A,R0	OR A,R0	MOV R0,#d8	CMP R0,#d8	SETB dir: 0	BBS dir: 0,rel	INC R0	DEC R0	CALLV #0	BNC rel
9		MOV A,R1	CMP A,R1	ADDC A,R1	SUBC A,R1	MOV R1,A	XOR A,R1	AND A,R1	OR A,R1	MOV R1,#d8	CMP R1,#d8	SETB dir: 1	BBS dir: 1,rel	INC R1	DEC R1	CALLV #1	BC rel
A		MOV A,R2	CMP A,R2	ADDC A,R2	SUBC A,R2	MOV R2,A	XOR A,R2	AND A,R2	OR A,R2	MOV R2,#d8	CMP R2,#d8	SETB dir: 2	BBS dir: 2,rel	INC R2	DEC R2	CALLV #2	BP rel
B		MOV A,R3	CMP A,R3	ADDC A,R3	SUBC A,R3	MOV R3,A	XOR A,R3	AND A,R3	OR A,R3	MOV R3,#d8	CMP R3,#d8	SETB dir: 3	BBS dir: 3,rel	INC R3	DEC R3	CALLV #3	BN rel
C		MOV A,R4	CMP A,R4	ADDC A,R4	SUBC A,R4	MOV R4,A	XOR A,R4	AND A,R4	OR A,R4	MOV R4,#d8	CMP R4,#d8	SETB dir: 4	BBS dir: 4,rel	INC R4	DEC R4	CALLV #4	BNZ rel
D		MOV A,R5	CMP A,R5	ADDC A,R5	SUBC A,R5	MOV R5,A	XOR A,R5	AND A,R5	OR A,R5	MOV R5,#d8	CMP R5,#d8	SETB dir: 5	BBS dir: 5,rel	INC R5	DEC R5	CALLV #5	BZ rel
E		MOV A,R6	CMP A,R6	ADDC A,R6	SUBC A,R6	MOV R6,A	XOR A,R6	AND A,R6	OR A,R6	MOV R6,#d8	CMP R6,#d8	SETB dir: 6	BBS dir: 6,rel	INC R6	DEC R6	CALLV #6	BGE rel
F		MOV A,R7	CMP A,R7	ADDC A,R7	SUBC A,R7	MOV R7,A	XOR A,R7	AND A,R7	OR A,R7	MOV R7,#d8	CMP R7,#d8	SETB dir: 7	BBS dir: 7,rel	INC R7	DEC R7	CALLV #7	BLT rel

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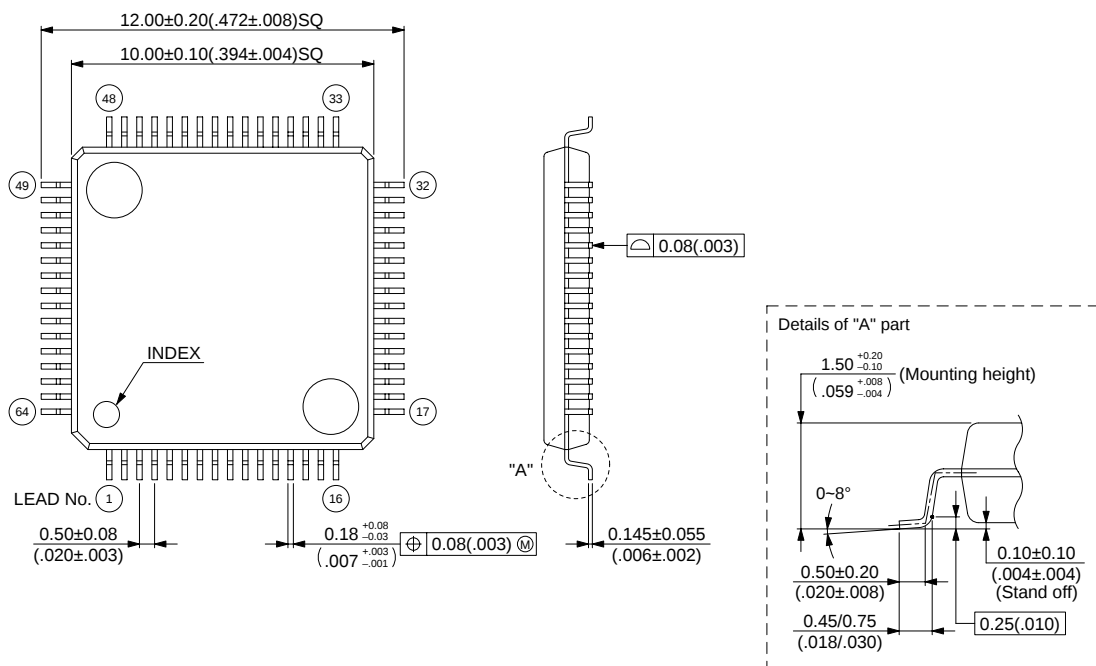
Part number	Package	Remarks
MB89593BPFV MB89595BPFV MB89P595BPFV MB89593BWPFV MB89595BWPFV MB89P595BWPFV	64-pin plastic LQFP (FPT-64P-M03)	

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■ PACKAGE DIMENSION

64-pin plastic LQFP
(FPT-64P-M03)

Note: Pins width and pins thickness include plating thickness.



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Dimensions in mm (inches)

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